# -3.3V / -5V Differential ECL to +3.3V LVTTL Translator

# Description

The MC100EPT25 is a Differential ECL to LVTTL translator. This device requires +3.3 V, -3.3 V to -5.2 V, and ground. The small outline 8-lead package and the single gate of the EPT25 make it ideal for applications which require the translation of a clock or data signal.

The  $V_{BB}$  output allows the EPT25 to also be used in a single–ended input mode. In this mode the  $V_{BB}$  output is tied to the D input for a inverting buffer or the  $\overline{D}$  input for a non–inverting buffer. If used, the  $V_{BB}$  pin should be bypassed to ground with at least a 0.01  $\mu F$  capacitor.

#### **Features**

- 1.1 ns Typical Propagation Delay
- Maximum Frequency > 275 MHz Typical
- Operating Range:  $V_{CC} = 3.0 \text{ V}$  to 3.6 V;  $V_{EE} = -5.5 \text{ V}$  to -3.0 V; GND = 0 V
- 24 mA TTL Outputs
- Q Output Will Default LOW with Inputs Open or at V<sub>EE</sub>
- V<sub>BB</sub> Output
- Open Input Default State
- Safety Clamp on Inputs
- Pb-Free Packages are Available



# ON Semiconductor®

http://onsemi.com

#### **MARKING DIAGRAMS\***



SOIC-8 D SUFFIX CASE 751





TSSOP-8 DT SUFFIX CASE 948R





DFN8 MN SUFFIX CASE 506AA



A = Assembly Location

L = Wafer Lot Y = Year

W = Work Week

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*For additional marking information, refer to Application Note AND8002/D.

# **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

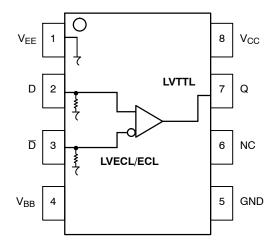


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

# **Table 1. PIN DESCRIPTION**

PIN	FUNCTION
Q	LVTTL Output
D*, <u>D</u> *	Differential ECL Input Pair
V <sub>CC</sub>	Positive Supply
V <sub>BB</sub>	Output Reference Voltage
GND	Ground
V <sub>EE</sub>	Negative Supply
NC	No Connect
EP	(DFN8 only) Thermal exposed pad must be connected to a sufficient thermal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open.

<sup>\*</sup> Pins will default LOW when left open.

Table 2. ATTRIBUTES

Characte	Value			
Internal Input Pulldown Resistor	75 kΩ			
Internal Input Pullup Resistor		N,	/A	
ESD Protection	> 4 > 20 > 2			
Moisture Sensitivity, Indefinite Tim	ne Out of Drypack (Note 1)	Pb Pkg	Pb-Free Pkg	
	Level 1 Level 1 Level 1	Level 1 Level 3 Level 1		
Flammability Rating	UL-94 V-0	@ 0.125 in		
Transistor Count	111 D	evices		
Meets or exceeds JEDEC Spec E	IA/JESD78 IC Latchup Test			

<sup>1.</sup> For additional information, see Application Note AND8003/D.

**Table 3. MAXIMUM RATINGS** 

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	Positive Power Supply	GND = 0 V	V <sub>EE</sub> = −5.0 V	3.8	V
V <sub>EE</sub>	Negative Power Supply	GND = 0 V	V <sub>CC</sub> = +3.3 V	-6	V
V <sub>IN</sub>	Input Voltage	GND = 0 V		0 to V <sub>EE</sub>	V
I <sub>BB</sub>	V <sub>BB</sub> Sink/Source			± 0.5	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	8 SOIC 8 SOIC	190 130	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	8 SOIC	41 to 44	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	8 TSSOP 8 TSSOP	185 140	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	8 TSSOP	41 to 44	°C/W
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN8 DFN8	129 84	°C/W °C/W
T <sub>sol</sub>	Wave Solder Pb Pb-Free	<2 to 3 sec @ 248°C <2 to 3 sec @ 260°C		265 265	°C
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	(Note 2)	DFN8	35 to 40	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

2. JEDEC standard multilayer board - 2S2P (2 signal, 2 power)

Table 4. NECL DC CHARACTERISTICS  $V_{CC} = 3.3 \text{ V}$ ;  $V_{EE} = -5.5 \text{ V}$  to -3.0 V; GND = 0.0 V (Note 3)

		-40°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current	8.0	16	25	8.0	16	25	8.0	16	25	mA
V <sub>IH</sub>	Input HIGH Voltage Single-Ended	-1225		-880	-1225		-880	-1225		-880	mV
V <sub>IL</sub>	Input LOW Voltage Single-Ended	-1945		-1625	-1945		-1625	-1945		-1625	mV
$V_{BB}$	Output Voltage Reference	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Note 4)	V <sub>EE</sub> .	+ 2.0	0.0	V <sub>EE</sub> .	+ 2.0	0.0	V <sub>EE</sub> -	+ 2.0	0.0	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 3. Input parameters vary 1:1 with GND.
- 4. V<sub>IHCMR</sub> min varies 1:1 with V<sub>EE</sub>, V<sub>IHCMR</sub> max varies 1:1 with V<sub>CC</sub>. The V<sub>IHCMR</sub> range is referenced to the most positive side of the differential input signal.

Table 5. TTL OUTPUT DC CHARACTERISTICS  $V_{CC} = 3.3 \text{ V}; V_{EE} = -5.5 \text{ V} \text{ to } -3.0 \text{ V}; \text{GND} = 0.0 \text{ V}; T_A = -40 ^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C}$ 

Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V <sub>OH</sub>	Output HIGH Voltage	I <sub>OH</sub> = −3.0 mA	2.2			V
$V_{OL}$	Output LOW Voltage	I <sub>OL</sub> = 24 mA			0.5	V
I <sub>CCH</sub>	Power Supply Current		6	10	14	mA
I <sub>CCL</sub>	Power Supply Current		7	12	17	mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

Table 6. AC CHARACTERISTICS  $V_{CC} = 3.0 \text{ V}$  to 3.6 V;  $V_{EE} = -5.5 \text{ V}$  to -3.0 V; GND = 0.0 V (Note 5)

		–40°C		25°C		85°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Frequency (See Figure 2 F <sub>max</sub> /JITTER)	275			275			275			MHz
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay to Output Differential (Cross-Point to 1.5 V)	500	950	1300	800	950	1600	800	960	1600	ps
t <sub>SKPP</sub>	Device-to-Device Skew (Note 6)			500			500			500	ps
t <sub>UITTER</sub>	Random Clock Jitter (RMS) (See Figure 2 F <sub>max</sub> /JITTER)		0.2	< 1		0.2	< 1		0.2	< 1	ps
V <sub>PP</sub>	Input Voltage Swing (Differential)	150	800	1200	150	800	1200	150	800	1200	mV
t <sub>r</sub>	Output Rise/Fall Times Q, $\overline{\mathbb{Q}}$ (0.8 V – 2.0 V)	300 900	474 1160	600 1400	300 900	459 1100	600 1400	300 900	457 1100	600 1400	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 5. Measured with a 750 mV 50% duty-cycle clock source.  $R_L$  = 500  $\Omega$  to GND and  $C_L$  = 20 pF to GND. Refer to Figure 3.
- 6. Skews are measured between outputs under identical conditions.

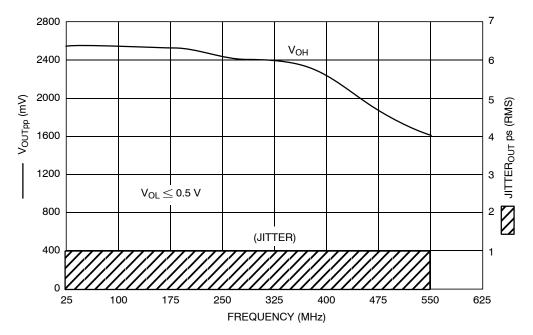


Figure 2. F<sub>max</sub>/Jitter

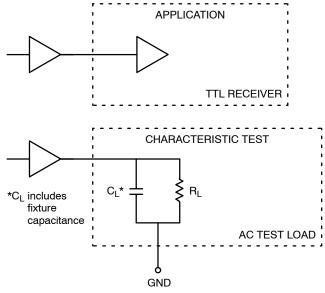


Figure 3. TTL Output Loading Used for Device Evaluation

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC100EPT25D	SOIC-8	98 Units / Rail
MC100EPT25DG	SOIC-8 (Pb-Free)	98 Units / Rail
MC100EPT25DR2	SOIC-8	2500 / Tape & Reel
MC100EPT25DR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC100EPT25DT	TSSOP-8	100 Units / Rail
MC100EPT25DTG	TSSOP-8 (Pb-Free)	100 Units / Rail
MC100EPT25DTR2	TSSOP-8	2500 / Tape & Reel
MC100EPT25DTR2G	TSSOP-8 (Pb-Free)	2500 / Tape & Reel
MC100EPT25MNR4	DFN8	1000 / Tape & Reel
MC100EPT25MNR4G	DFN8 (Pb-Free)	1000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **Resource Reference of Application Notes**

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family

AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide
AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

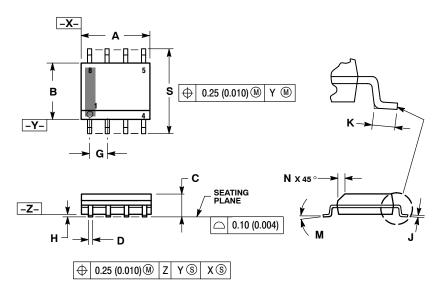
AND8020/D - Termination of ECL Logic Devices

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

#### PACKAGE DIMENSIONS

## SOIC-8 NB CASE 751-07 **ISSUE AJ**

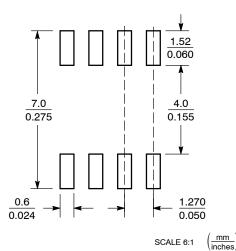


#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSION A AND B DO NOT INCLUDE
  MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- PER SIDE.
  DIMENSION D DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL
  IN EXCESS OF THE D DIMENSION AT
  MAXIMUM MATERIAL CONDITION.
  751-01 THRU 751-06 ARE OBSOLETE. NEW
  STANDARD IS 751-07.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	7 BSC	0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

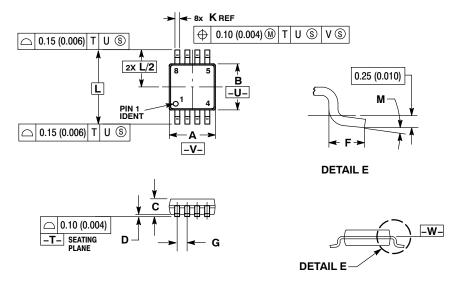
# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

#### TSSOP-8 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948R-02 **ISSUE A**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

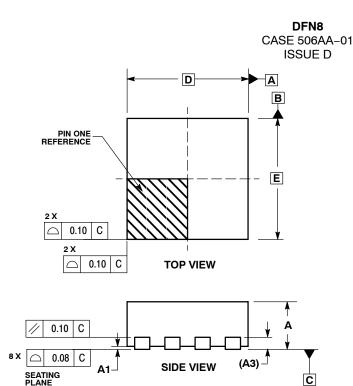
  - PER SIDE.

    5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

    6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W-.

	MILLIN	IETERS	INC	HES
DIM	MIN	MIN MAX		MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65	BSC	0.026	BSC
K	0.25	0.40	0.010	0.016
۲	4.90	BSC	0.193	BSC
M	0°	6 °	0°	6°

#### PACKAGE DIMENSIONS



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED
- TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS				
DIM	MIN	MAX			
Α	0.80	1.00			
A1	0.00	0.05			
A3	0.20	REF			
b	0.20	0.30			
D	2.00	BSC			
D2	1.10	1.30			
E	2.00	BSC			
E2	0.70	0.90			
е	0.50 BSC				
K	0.20				
L	0.25	0.35			

ECLinPS is a trademark of Semiconductor Components Industries, LLC (SCILLC).

**BOTTOM VIEW** 

e/2

Κ

ON Semiconductor and 📖 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

е

**E2** 

Ф

0.10 С A B

С 0.05

NOTE 3

5

## **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

MC100EPT25/D